

N-channel TrenchMOS standard level FET 19 May 2016

**Product data sheet** 

#### **General description** 1.

Standard level N-channel MOSFET in a SOT226 package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

#### **Features and benefits** 2.

- AEC Q101 compliant •
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with  $V_{GS(th)}$  rating of greater than 1 V at 175 °C •

### 3. Applications

- 12 V Automotive systems
- Electric and electro-hydraulic power steering
- Motors, lamps and solenoid control
- Start-Stop micro-hybrid applications •
- Transmission control
- Ultra high performance power switching •

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	40	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	120	А
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	-	324	W
Static charact	eristics	I			- 1		
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11		-	1.5	1.9	mΩ
Dynamic char	acteristics						
Q <sub>GD</sub>	gate-drain charge	$I_D$ = 25 A; $V_{DS}$ = 32 V; $V_{GS}$ = 10 V; Fig. 13; Fig. 14		-	34.7	-	nC

[1] Continuous current is limited by package.

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#### N-channel TrenchMOS standard level FET

### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain		
3	S	source		G - UFI A
mb	D	mounting base; connected to drain	I 2 3 I 2PAK (SOT226)	mbb076 S

### 6. Ordering information

Table 3.   Ordering information						
Type number Package						
	Name	Description	Version			
BUK7E1R9-40E	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226			

### 7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK7E1R9-40E	BUK7E1R9-40E

### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	40	V
V <sub>DGR</sub>	drain-gate voltage	R <sub>GS</sub> = 20 kΩ		-	40	V
V <sub>GS</sub>	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	324	W
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	120	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 2</u>	[1]	-	120	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^\circ C$ ; Fig. 3		-	1198	А
T <sub>stg</sub>	storage temperature			-55	175	°C

#### N-channel TrenchMOS standard level FET

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
Source-drai	in diode				- 1	
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	120	А
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^\circ C$		-	1198	А
Avalanche	ruggedness					
E <sub>DS(AL)S</sub>	non-repetitive drain-source avalanche energy	$\begin{split} & I_{D} = 120 \; A;  V_{sup} \leq 40 \; V;  R_{GS} = 50 \; \Omega; \\ & V_{GS} = 10 \; V;  T_{j(init)} = 25 \; ^{\circ}C; \; unclamped; \\ & \overline{Fig. 4} \end{split}$	[2][3]	-	801	mJ

[1] Continuous current is limited by package.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

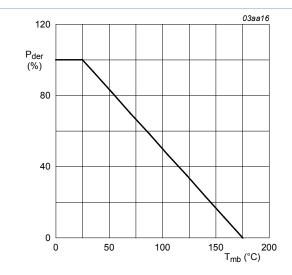
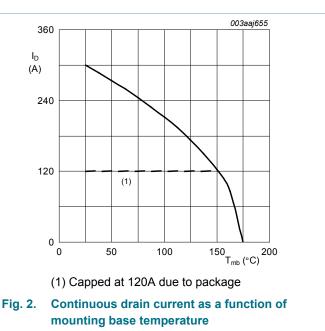


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

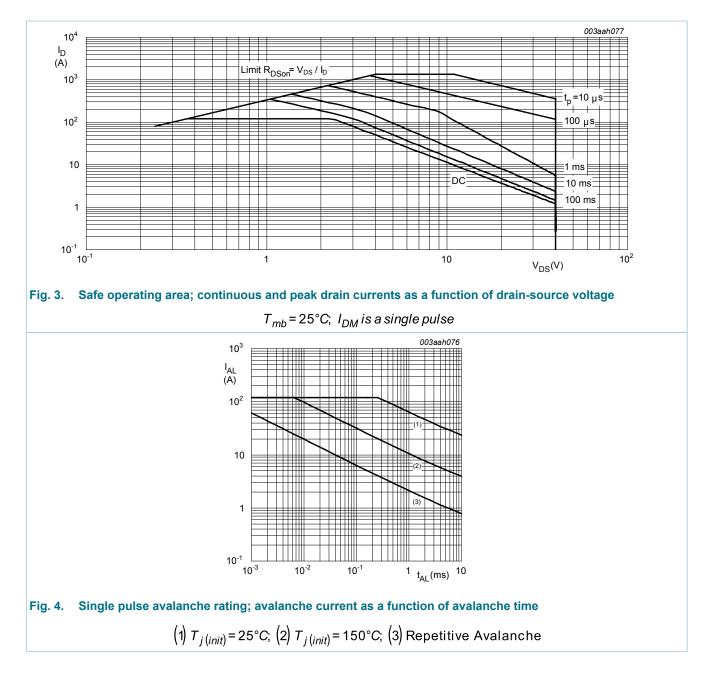
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$



 $V_{GS} \ge 10V$ 

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#### N-channel TrenchMOS standard level FET



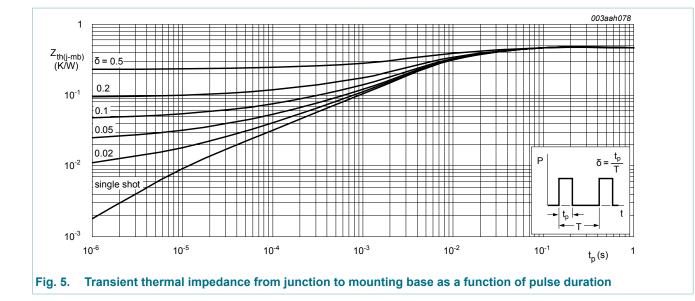
### 9. Thermal characteristics

Iable 6.   I hermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	0.46	K/W	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	vertical in still air		-	65	-	K/W	

#### Table 6. Thermal characteristics

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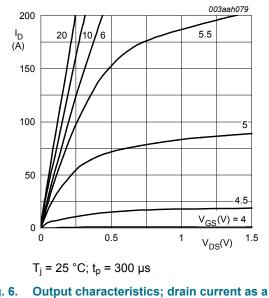


### **10. Characteristics**

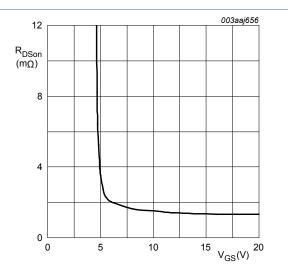
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · ·	I			
V <sub>(BR)DSS</sub>	drain-source	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	40	-	-	V
	breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = -55 °C	36	-	-	V
V <sub>GS(th)</sub> gate-source threshold voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 25 °C; <u>Fig. 9;</u> <u>Fig. 10</u>	2.4	3	4	V	
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10	-	-	4.5	V
	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 10	1	-	-	V	
I <sub>DSS</sub> drain leakage current	$V_{DS}$ = 40 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	0.27	3	μA	
	$V_{DS}$ = 40 V; $V_{GS}$ = 0 V; $T_j$ = 175 °C	-	-	500	μA	
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 11	-	1.5	1.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 12; Fig. 11	-	-	3.6	mΩ
Dynamic cl	naracteristics	· · ·	I			
Q <sub>G(tot)</sub>	total gate charge	$I_D$ = 25 A; $V_{DS}$ = 32 V; $V_{GS}$ = 10 V;	-	118	-	nC
Q <sub>GS</sub>	gate-source charge	Fig. 13; Fig. 14	-	29.3	-	nC
Q <sub>GD</sub>	gate-drain charge		-	34.7	-	nC

#### N-channel TrenchMOS standard level FET

Symbol	Parameter	Conditions	ſ	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{DS}$ = 25 V; $V_{GS}$ = 0 V; f = 1 MHz;		-	7873	10472	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 15</u>		-	1410	1692	pF
C <sub>rss</sub>	reverse transfer capacitance	$V_{DS}$ = 30 V; R <sub>L</sub> = 1.2 Ω; V <sub>GS</sub> = 10 V; R <sub>G(ext)</sub> = 5 Ω		-	851	1165	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 30 V; R <sub>L</sub> = 1.2 Ω; V <sub>GS</sub> = 10 V;		-	35	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega$		-	49	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	87	-	ns
t <sub>f</sub>	fall time			-	52	-	ns
L <sub>D</sub>	internal drain inductance	from upper edge of drain mounting base to center of die		-	2.5	-	nH
L <sub>S</sub>	internal source inductance	from source lead to source bonding pad		-	7.5	-	nH
Source-dra	in diode	· · · · · ·	I			1	
V <sub>SD</sub>	source-drain voltage	$I_{S}$ = 25 A; $V_{GS}$ = 0 V; $T_{j}$ = 25 °C; <u>Fig. 16</u>		-	0.79	1.2	V
t <sub>rr</sub>	reverse recovery time	$I_{\rm S}$ = 20 A; dI_{\rm S}/dt = -100 A/µs; V <sub>GS</sub> = 0 V;		-	46	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 25 V		-	62	-	nC





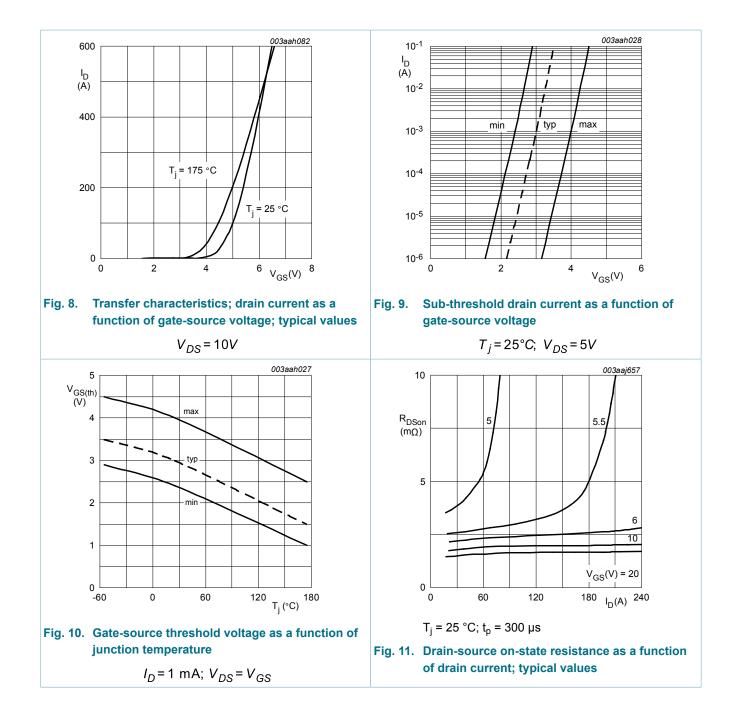




 $T_j = 25^{\circ}C; I_D = 25A$ 

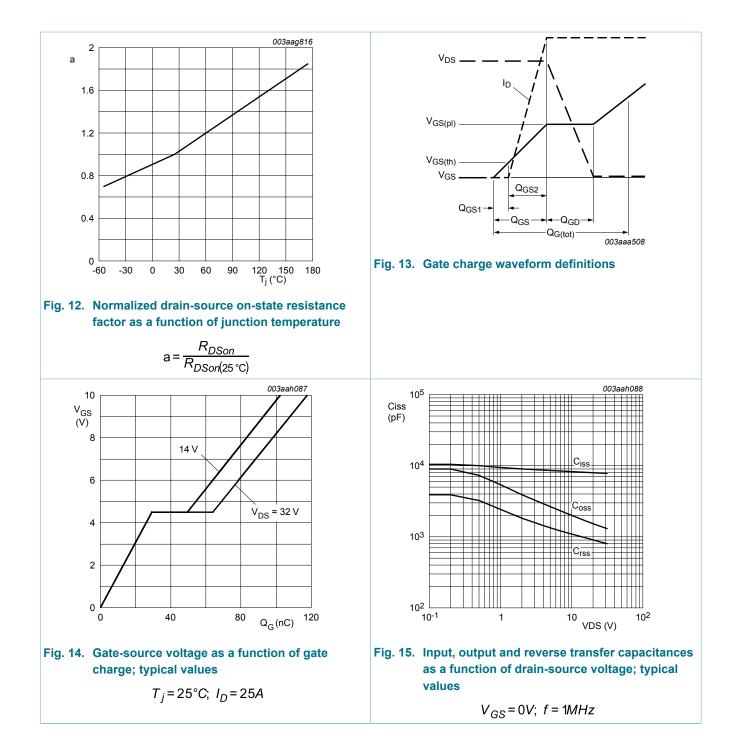
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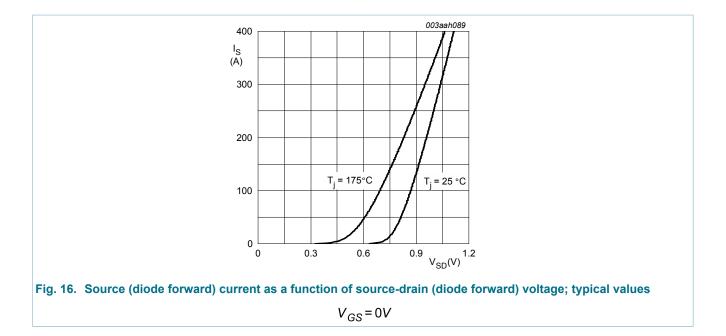
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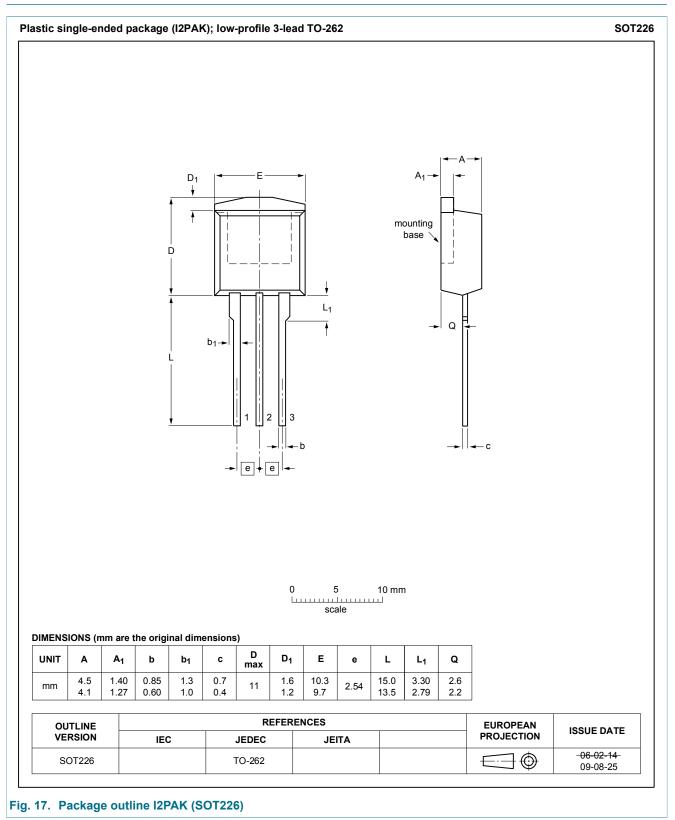
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### 11. Package outline



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#### 12. Legal information

#### 12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### **13. Contents**

General description	I
Features and benefits	1
Applications 1	
Quick reference data	1
Pinning information	2
Ordering information	2
Marking2	2
Limiting values	2
Thermal characteristics	1
Characteristics	5
Package outline10	)
Legal information11	I
Data sheet status1	1
Definitions11	
Disclaimers11	
Trademarks 12	2
	General description 1   Features and benefits 1   Applications 1   Quick reference data 1   Pinning information 2   Ordering information 2   Limiting values 2   Thermal characteristics 2   Characteristics 2   Package outline 10   Legal information 11   Data sheet status 11   Disclaimers 11   Trademarks 12

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